



SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

SB007-03C — Schottky Barrier Diode 30V, 70mA Rectifier

Applications

- High frequency rectification (switching regulators, converters, choppers).

Features

- Low forward voltage (V_F max=0.55V).
- Fast reverse recovery time (t_{rr} max=10ns).
- Low switching noise.
- Low leakage current and high reliability due to highly reliable planar structure.

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		30	V
Nonrepetitive Peak Reverse Surge Voltage	V_{RSM}		35	V
Average Output Current	I_O		70	mA
Surge Forward Current	I_{FSM}	50Hz sine wave, 1 cycle	2	A
Junction Temperature	T_J		-55 to +125	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +125	$^\circ\text{C}$

Marking : G

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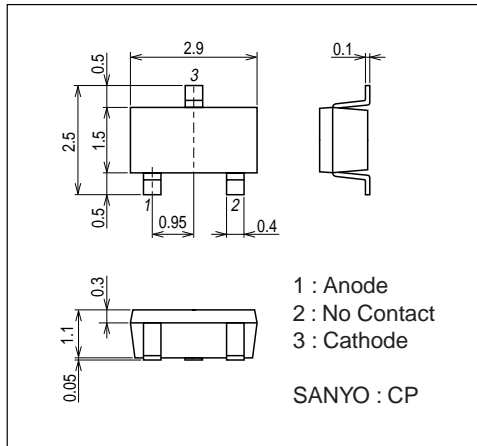
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	V _R	I _R =20μA, T _j =25°C	30			V
Forward Voltage	V _F	I _F =70mA, T _j =25°C			0.55	V
Reverse Current	I _R	V _R =15V, T _j =25°C			5	μA
Interterminal Capacitance	C	V _R =10V, f=1MHz		3.0		pF
Reverse Recovery Time	t _{rr}	I _F =I _R =10mA, T _j =25°C, See specified Test Circuit.			10	ns
Thermal Resistance	Rthj-a(1)			620		°C / W
	Rthj-a(2)	Mounted in Cu-foiled area of 16mm²×0.2mm on glass epoxy board		430		°C / W

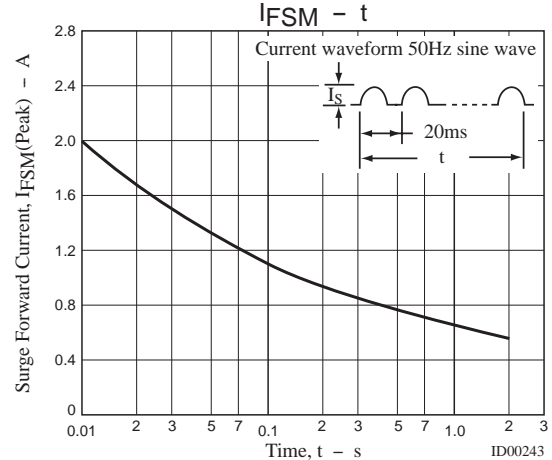
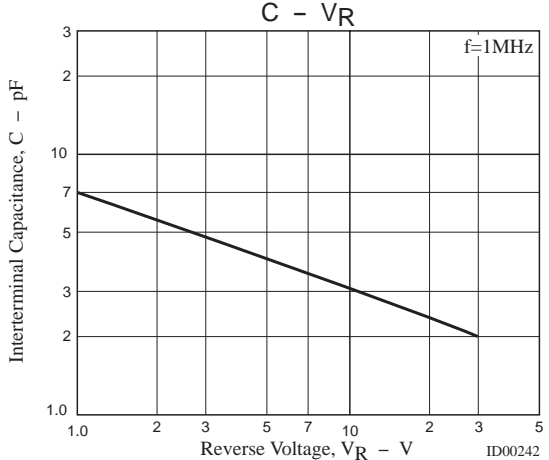
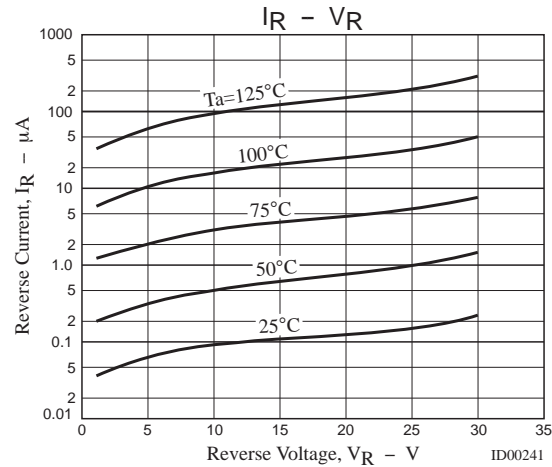
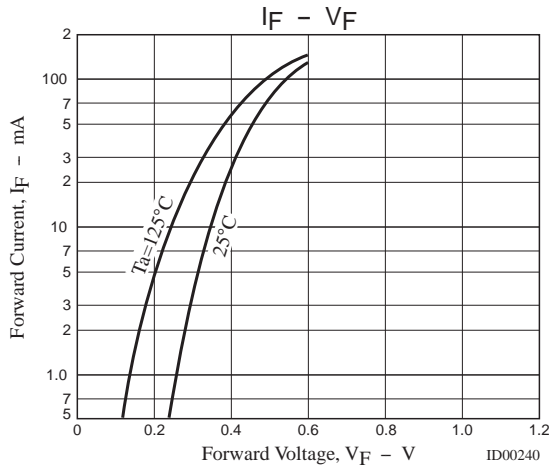
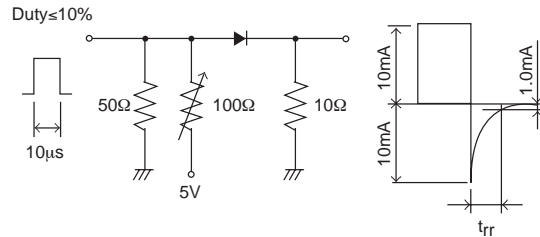
Package Dimensions

unit : mm (typ)

7013A-004



t_{rr} Test Circuit



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